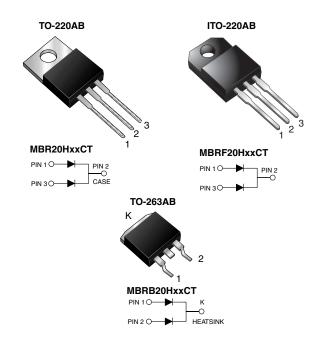


MBR20HxxCT, MBRF20HxxCT, MBRB20HxxCT

Vishay General Semiconductor

Dual Common Cathode Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS						
I _{F(AV)}	2 x 10 A					
V _{RRM}	35 V to 60 V					
I _{FSM}	I _{FSM} 150 A					
V _F	0.55 V, 0.61 V					
I _R	100 µA					
T _J max.	175 °C					
Package	TO-220AB, ITO-220AB, TO-263AB					
Diode variations	Common cathode					

FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

MECHANICAL DATA

Case: TO-220AB, ITO-220AB, TO-263AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade Base P/NHE3 - RoHS-compliant, AEC-Q101 qualified

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test, HE3 suffix meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum



Revision: 12-Jun-13

Document Number: 88787

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



www.vishay.com

Vishay General Semiconductor

MAXIMUM RATINGS ($T_c = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	MBR20H35CT	MBR20H45CT	MBR20H50CT	MBR20H60CT	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	35	45	50 60				
Working peak reverse voltage	V _{RWM}	35	45	50	60	V		
Maximum DC blocking voltage	V _{DC}	35	45	50 60				
Maximum average forward rectified total device		20						
current (fig. 1) per diode	I _{F(AV)}	10						
Non-repetitive avalanche energy per diode at 25 °C, I_{AS} = 4 A, L = 10 mH	E _{AS}	80				mJ		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	150						
Peak repetitive reverse surge current per diode at t_{p} = 2.0 $\mu\text{s},$ 1 kHz	I _{RRM}	1.0 0.5				A		
Peak non-repetitive reverse energy (8/20 μs waveform)	E _{RSM}	20 10				mJ		
Electrostatic discharge capacitor voltage Human body model: C = 100 pF, R = 1.5 k Ω	V _C	25						
Voltage rate of change (rated V _R)	dV/dt	10 000						
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to 175				°C		
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V _{AC}	1500			V			

ELECTRICAL CHARACTERISTICS ($T_C = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MBR20H35CT MBR20H45CT		MBR20H50CT MBR20H60CT		UNIT
				TYP.	MAX.	TYP.	MAX.	
Maximum instantaneous forward voltage per diode	V _F ⁽¹⁾	$I_{F} = 10 \text{ A}$	T _C = 25 °C	-	0.63	-	0.71	
		I _F = 10 A	T _C = 125 °C	0.49	0.55	0.57	0.61	v
		I _F = 20 A	T _C = 25 °C	-	0.75	-	0.85	v
				$I_{F} = 20 \text{ A}$	T _C = 125 °C	0.62	0.68	0.68
Maximum reverse current per diode	I _R ⁽²⁾	(2) Rated V _B	T _J = 25 °C	-	100	-	100	μA
			T _J = 125 °C	4.0	12	2.0	12	mA

Notes

⁽¹⁾ Pulse test: 300 µs pulse width, 1 % duty cycle

 $^{(2)}$ Pulse test: Pulse width $\leq 40\mbox{ ms}$

THERMAL CHARACTERISTICS ($T_c = 25 \text{ °C}$ unless otherwise noted)						
ARAMETER SYMBOL MBR MBRF MBRB UNIT						
Typical resistance, junction to case per diode	$R_{\theta JC}$	2.0	4.0	2.0	°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	MBR20H45CT-E3/45	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H45CT-E3/45	1.99	45	50/tube	Tube		
TO-263AB	MBRB20H45CT-E3/45	1.35	45	50/tube	Tube		
TO-263AB	MBRB20H45CT-E3/81	1.35	81	800/reel	Tape and reel		
TO-220AB	MBR20H45CTHE3/45 ⁽¹⁾	1.85	45	50/tube	Tube		
ITO-220AB	MBRF20H45CTHE3/45 ⁽¹⁾	1.99	45	50/tube	Tube		
TO-263AB	MBRB20H45CTHE3/45 (1)	1.35	45	50/tube	Tube		
TO-263AB	MBRB20H45CTHE3/81 (1)	1.35	81	800/reel	Tape and reel		

Note

(1) AEC-Q101 qualified

Revision: 12-Jun-13

Document Number: 88787

For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u> www.vishay.com

MBR20HxxCT, MBRF20HxxCT, MBRB20HxxCT

Vishay General Semiconductor

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

ISHA

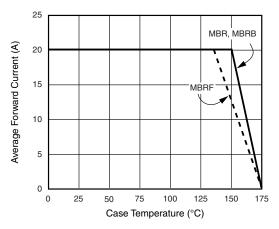


Fig. 1 - Forward Current Derating Curve (Total)

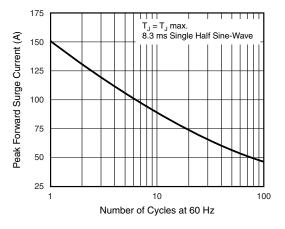
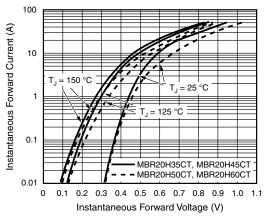
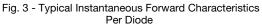


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode





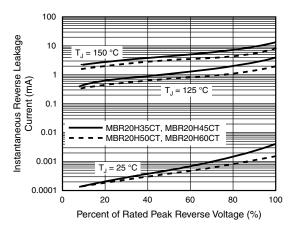


Fig. 4 - Typical Reverse Characteristics Per Diode

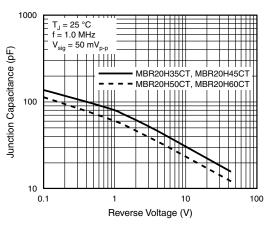
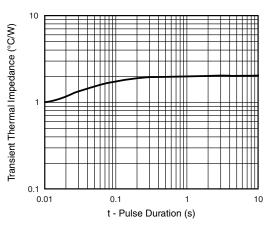


Fig. 5 - Typical Junction Capacitance Per Diode





Revision: 12-Jun-13

Document Number: 88787

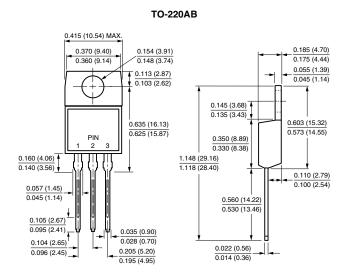
For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

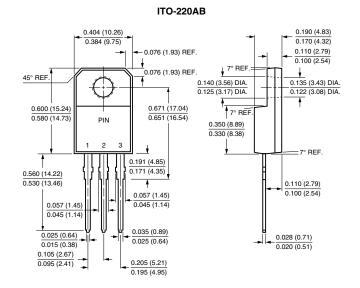


MBR20HxxCT, MBRF20HxxCT, MBRB20HxxCT

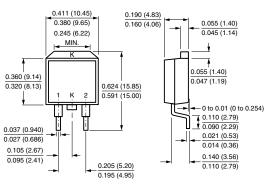
Vishay General Semiconductor

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

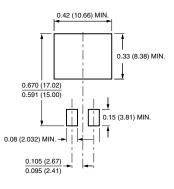




TO-263AB



Mounting Pad Layout





Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Vishay:

 MBRB20H35CTHE3/45
 MBRB20H35CTHE3/81
 MBR20H35CT-E3/45
 MBR20H45CT-E3/45
 MBR20H45CTHE3/45

 MBR20H60CT-E3/45
 MBR20H60CTHE3/45
 MBRB20H45CT/31
 MBRB20H45CT/81
 MBRB20H45CT-E3/31

 MBRB20H45CT-E3/81
 MBRB20H45CTHE3/81
 MBRB20H60CT-E3/81
 MBRB20H60CTHE3/81
 MBRF20H45CT-E3/81

 MBRF20H45CTHE3/45
 MBRF20H60CT-E3/45
 MBRF20H60CT-E3/81
 MBRF20H45CT/E3/81
 MBRF20H45CT/E3/81

 MBRF20H45CTHE3/45
 MBRF20H60CT-E3/45
 MBRF20H60CTHE3/45
 MBR20H45CT/45
 MBR20H60CT/45

 MBRB20H35CT-E3/45
 MBRB20H35CT-E3/81
 MBRF20H60CT-E3/81
 MBR20H60CT/45
 MBR20H60CT/45